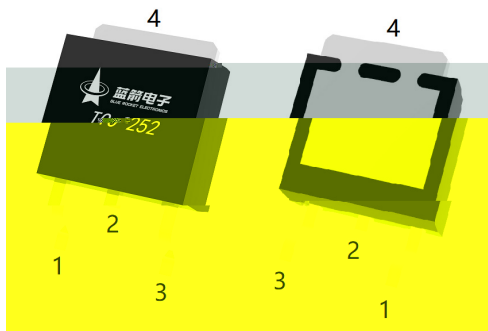
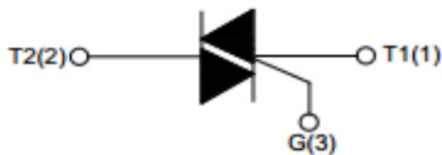


Triac in a TO-252 Plastic Package.

Medium current triac, Low on state voltage drop, High reliability and stability, Low thermal resistance, HF Product.

Suitable for general purpose AC switching .Such as static relays, heating regulation, induction motor starting circuits, motor speed controllers, etc.



PIN1 Main Terminal 1 PIN 2 4 Main Terminal 2 PIN 3 Gate

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Repetitive peak off-state/reverse voltages($T_j=125^\circ\text{C}$)	$V_{\text{DRM}}/V_{\text{RRM}}$	800	V
RMS on-state current($T_c=110^\circ\text{C}$)	$I_{\text{T(RMS)}}$	8	A
Non repetitive surge peak on-state current(full cycle, $T_j=25^\circ\text{C}$)	$I_{\text{TSM}(t=20\text{ms})}$	80	A
I^2t value for fusing($T_j=25^\circ\text{C}$)	$I^2t_{(tp=10\text{ms})}$	36	A^2s
Critical rate of rise of on-state current ($I_G=2I_{\text{GT}}$, $f=120\text{Hz}$ $T_j=125^\circ\text{C}$)	dI/dt I-II-III	50	$\text{A}/\mu\text{s}$
Peak gate current($t_p=20\mu\text{s}$ $T_j=125^\circ\text{C}$)	I_{GM}	4.0	A
Average gate power dissipation($T_j=125^\circ\text{C}$)	$P_{\text{G(AV)}}$	1	W
Operating junction temperature range	T_j	-40 125	
Storage junction temperature range	T_{stg}	-40 150	
Junction to ambient(AC)	$R_{\text{th(j-a)}}$	100	/W
Junction to case for(AC)	$R_{\text{th(j-c)}}$	3.1	

/ Electrical Characteristics($T_j=25^\circ\text{C}$)

3 / Snubberless and logic level 3 quadrants)

Symbol	Test Conditions	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=30\Omega$	I-II-III	Max.	35	mA
V_{GT}	$V_D=12\text{V}$ $R_L=30\Omega$	I-II-III	Max.	1.3	V
V_{GD}	$V_D=V_{\text{DRM}}$ $R_L=3.3\text{K}\Omega$ $T_j=125^\circ\text{C}$	I-II-III	Min.	0.2	V
I_{L}	$I_G=1.2I_{\text{GT}}$	I-III	Max.	50	mA
		II		60	
I_{H}	$I_{\text{T}}=100\text{mA}$		Max.	35	mA
(dV/dt)	$V_D=67\% V_{\text{DRM}}$ Gate Open	$T_j=125^\circ\text{C}$	Min.	400	$\text{V}/\mu\text{s}$
V_{TM}	$I_{\text{TM}}=11\text{A}$ $t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	Max.	1.55	V
I_{DRM}	$V_D=V_{\text{DRM}}$ $V_R=V_{\text{RRM}}$	$T_j=25^\circ\text{C}$		10	μA
I_{RRM}		$T_j=125^\circ\text{C}$		1	mA

/ Electrical Characteristic Curve

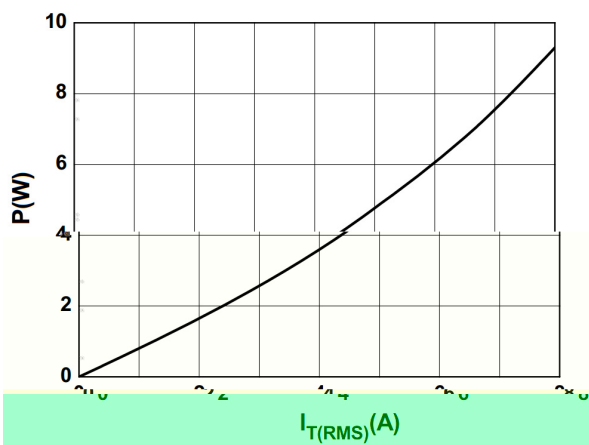


FIG.1 Maximum power dissipation versus RMS on-state current

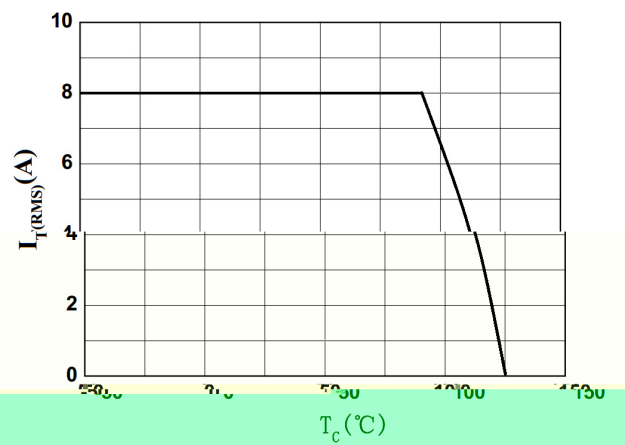


FIG.2: RMS on-state current versus case temperature

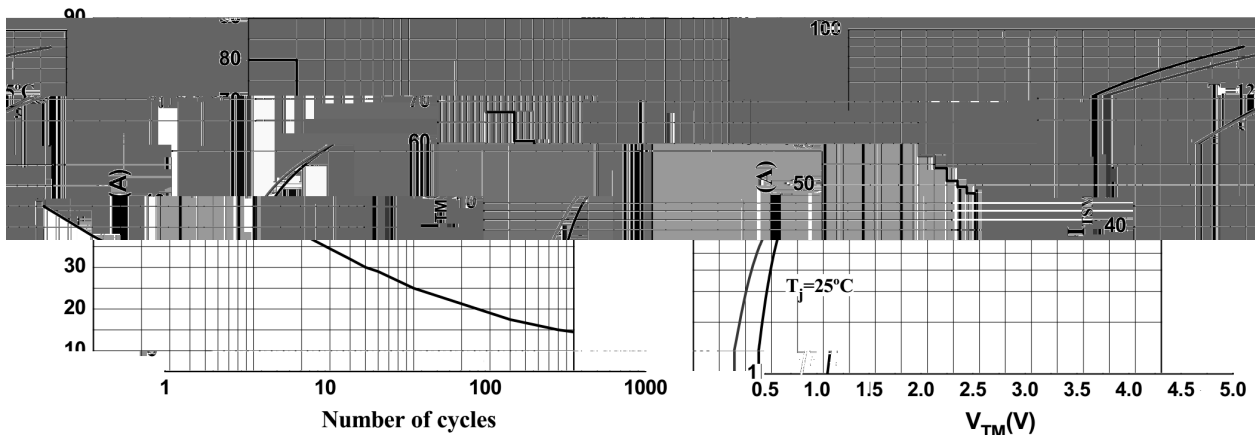


FIG.3: Surge peak on-state current versus number of cycles

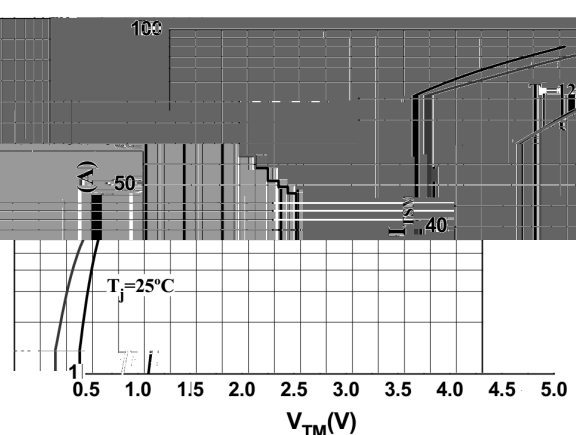


FIG.4: On-state characteristics

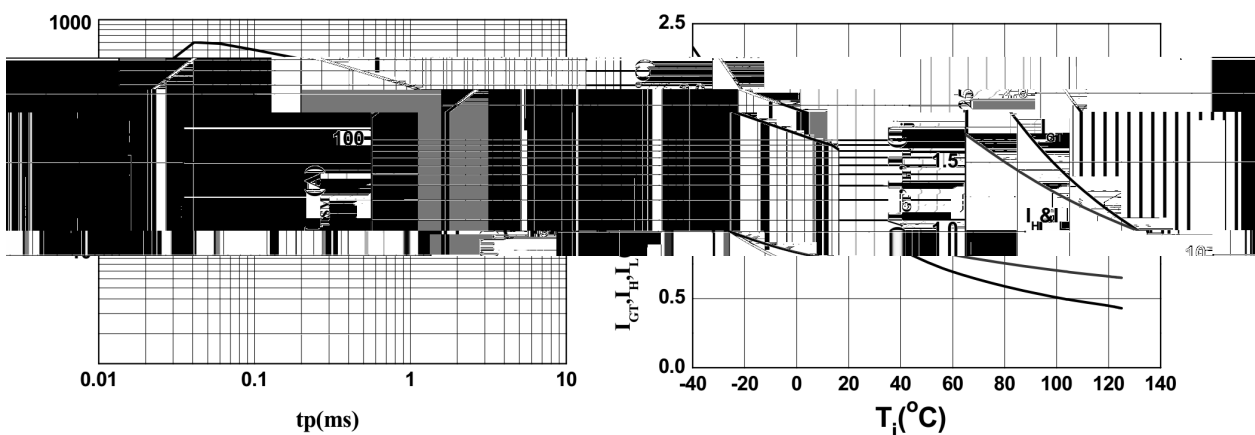
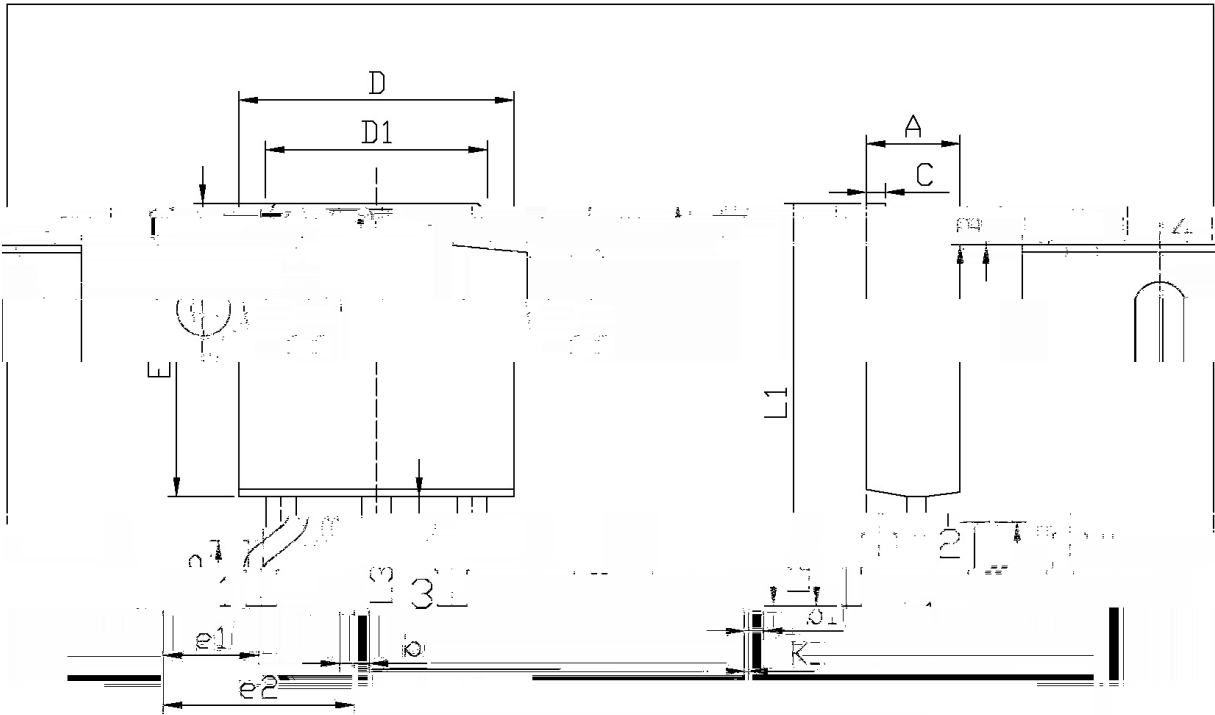


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p \leq 20\text{ms}$, and corresponding values of $dI/dt \leq 100\text{A}/\mu\text{s}$.

/ Package Dimensions



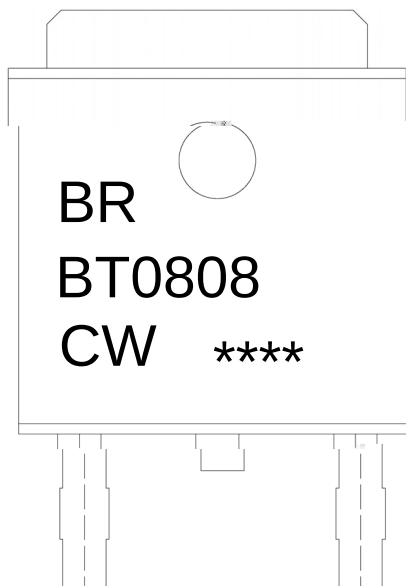
单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	2.20	2.40	E	5.95	6.25
B	0.95	1.25	e1	2.24	2.34
b	0.50	0.90	e2	4.43	4.73
b1	0.45	0.55	L1	9.45	9.95
C	0.45	0.55	L2	1.25	1.75
D	6.45	6.75	L3	0.60	0.90
D1	5.10	5.50	K	0.00	0.10

T0-252



/ Marking Instructions



Note:

BR: Company Code

BT0808: Product Type Code

CW: IGT Bracket Code

****: Lot No. Code, code change with Lot No

BRBT0808CWDP

Rev.A Oct.-2023



蓝箭电子
BLUE ROCKET ELECTRONICS

DATA SHEET